PNP -100mA -50V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V _{CC}	-50V
I _{C(MAX.)}	-100mA
R ₁	10kΩ
R_2	10kΩ

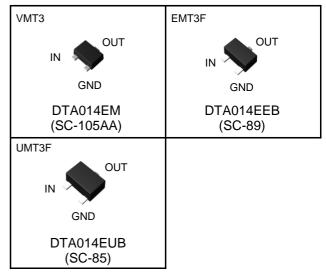
Features

- 1) Built-In Biasing Resistors, $R_1 = R_2 = 10k\Omega$.
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTC014E series
- 6) Lead Free/RoHS Compliant.

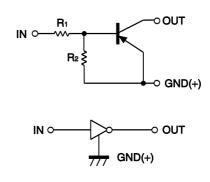
Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

Outline



•Inner circuit



Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTA014EM	VMT3	1212	T2L	180	8	8,000	30
DTA014EEB	EMT3F	1616	TL	180	8	3,000	30
DTA014EUB	UMT3F	2021	TL	180	8	3,000	30

● Absolute maximum ratings (Ta = 25°C)

Para	ameter	Symbol	Values	Unit
Supply voltage		V _{CC}	-50	V
Input voltage		V _{IN}	-40 to +10	V
Output current		I _O	-50	mA
Collector current		I _{C(MAX.)} *1	-100	mA
Power dissipation	DTA014EM DTA014EEB	P _D *2	150	mW
DTA014EUB		1	200	mW
Junction temperature		T _j	150	°C
Range of storage temper	ature	T _{stg}	-55 to +150	°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -0.1 \text{mA}$	-	-	-0.8	V
	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -5mA$	-2.6	-	1	V
Output voltage	$V_{O(on)}$	$I_0 / I_1 = -5 \text{mA} / -0.5 \text{mA}$	-	-0.07	-0.15	V
Input current	I _I	$V_1 = -5V$	-	-	-0.88	mA
Output current	I _{O(off)}	$V_{CC} = -50V, V_1 = 0V$	-	-	-0.5	μΑ
DC current gain	Gı	$V_{O} = -10V, I_{O} = -5mA$	35	-	-	-
Input resistance	R ₁	-	7	10	13	kΩ
Resistance ratio	R ₂ /R ₁	-	0.8	1	1.2	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	-	250	-	MHz

^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics) -100 INPUT VOLTAGE: V_{((on)} [V] Ta= -40°C -10 25°C 75°C -1 -0.1 -0.1 -100 OUTPUT CURRENT : Io [mA]

(OFF characteristics) -10 OUTPUT CURRENT : I_o [mA] 25°C 40°C -0.001 -0.5 -1.5 -3 0 INPUT VOLTAGE : $V_{I(off)}[V]$

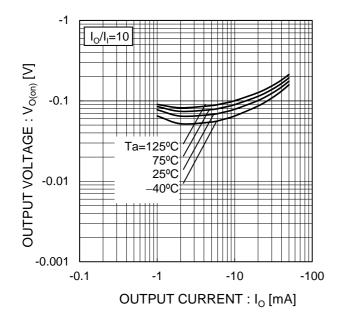
Fig.2 Output current vs. input voltage

Fig.3 Output current vs. output voltage

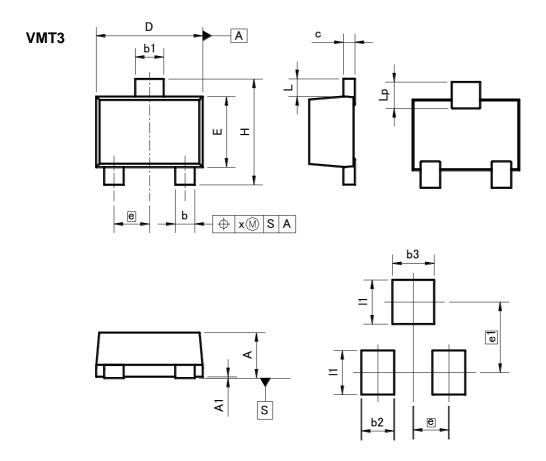
Fig.4 DC current gain vs. output current Ι_Ι= -500μΑ -450μΑ -400μΑ -50 1000 Ta=25°C -350µA $V_0 = -10V$ -40 -300µA OUTPUT CURRENT : Io [mA] -Ta=125°C 75°C DC CURRENT GAIN: G 100 25°C -30 200µA -20 10 -150µA -10 –100µA 0 0A -5 0 -0.1 -1 -10 -100 -10 OUTPUT VOLTAGE : Vo [V] OUTPUT CURRENT : Io [mA]

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



●Dimensions (Unit:mm)



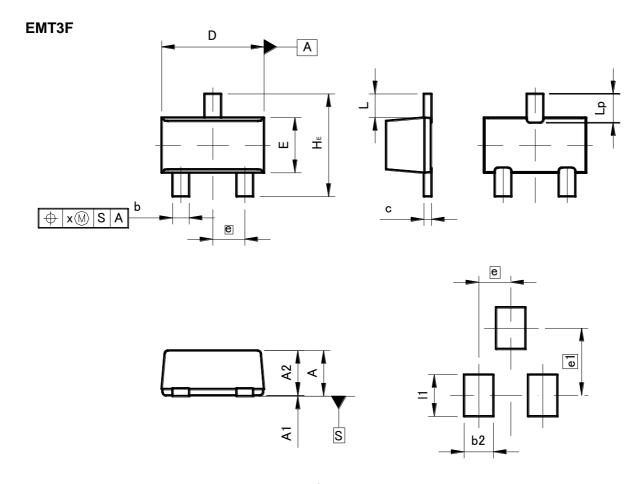
Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0	0.004	
b	0.17	0.27	0.007	0.011	
b1	0.27	0.37	0.011	0.015	
С	0.08	0.18	0.003	0.007	
D	1.10	1.30	0.043	0.051	
Е	0.70	0.90	0.028	0.035	
е	0.4	40	0.0	02	
HE	1.10	1.30	0.043	0.051	
L	0.10	0.30	0.004		
Lp	0.20	0.40	0.008	-	
x	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	0.80		0.03		
b2	_	0.37	ı	0.015	
b3	-	0.47	ı	0.019	
l1	_	0.50	ı	0.02	

Dimension in mm/inches

●Dimensions (Unit : mm)



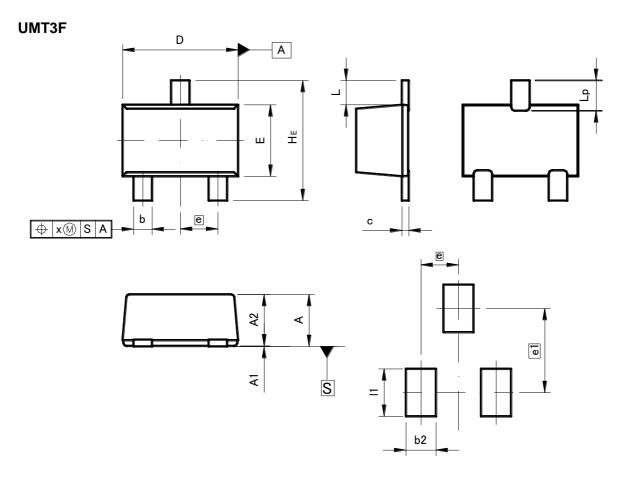
Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.65	0.85			
A1	0.00	0.10	0	0.004	
A2	0.60	0.80	0.024	0.031	
b	0.21	0.36	0.008	0.014	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
Е	0.76	0.96	0.03	0.038	
е	0.50		0.0	02	
HE	1.50	1.70	0.059	0.067	
L	0.37		0.0	15	
Lp	0.35	0.55	0.014	0.022	
X	_	0.10	_	0.004	

DIM		MILIMETERS		INCHES		
		MIN	MAX	MIN	MAX	
	e1	-	1.05	ı	0.041	
	b2	-	0.46	-	0.018	
I	1	-	0.65	-	0.026	

Dimension in mm/inches

●Dimensions (Unit:mm)



Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.85	1.05	0.033	0.041	
A1	0.00	0.10	0	0.004	
A2	0.80	1.00	0.031	0.039	
b	0.27	0.42	0.011	0.017	
С	0.08	0.18	0.003	0.007	
D	1.90	2.10	0.075	0.083	
Е	1.15	1.35	0.045	0.053	
е	0.0	65	0.0	03	
HE	2.00	2.20	0.079	0.087	
L	0.425		0.0	02	
Lp	0.43	0.63	0.017	0.025	
х	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
e1	1.47		0.058	
b2	_	0.52	_	0.02
11	_	0.83	_	0.033

Dimension in mm/inches

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